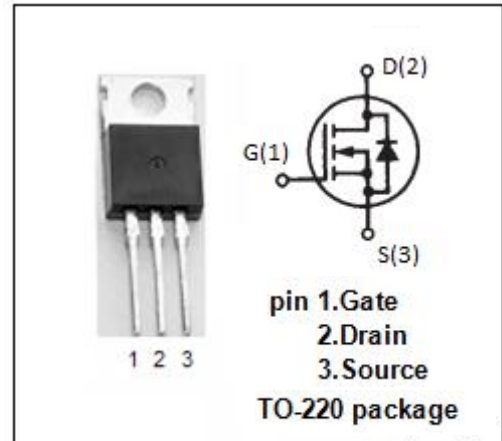


isc N-Channel MOSFET Transistor
STP11NM65N
FEATURES

- Drain Current $-I_D = 44A @ T_C = 25^\circ C$
- Drain Source Voltage-
: $V_{DSS} = 650V(\text{Min})$
- Static Drain-Source On-Resistance
: $R_{DS(on)} = 0.455 \Omega (\text{Max})$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation


APPLICATIONS

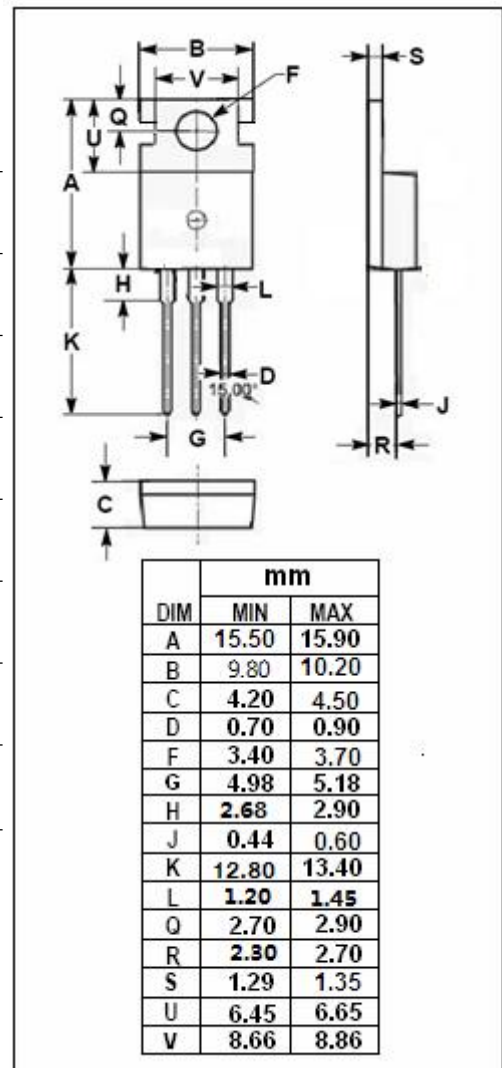
- Switching application

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	650	V
V_{GS}	Gate-Source Voltage-Continuous	± 25	V
I_D	Drain Current-Continuous	11	A
I_{DM}	Drain Current-Single Pluse	44	A
P_D	Total Dissipation @ $T_C = 25^\circ C$	110	W
T_J	Max. Operating Junction Temperature	-55~150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	1.14	$^\circ C/W$



isc N-Channel MOSFET Transistor

STP11NM65N

ELECTRICAL CHARACTERISTICS

 $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0$; $I_D=1\text{mA}$	650		V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$; $I_D=0.25\text{mA}$	2	4	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10\text{V}$; $I_D=5.5\text{A}$		0.455	Ω
I_{GSS}	Gate-Body Leakage Current	$V_{GS}=\pm 20\text{V}$; $V_{DS}=0$		± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=650\text{V}$; $V_{GS}=0$ $V_{DS}=650\text{V}$; $V_{GS}=0$; $T_j=125^{\circ}\text{C}$		1 100	μA
V_{SD}	Forward On-Voltage	$I_S=11\text{A}$; $V_{GS}=0$		1.6	V

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.